PATENT ASSIGNMENT

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date	
Hung-Lin Shih	10/01/2006	
Tsan-Chi Chu	10/01/2006	

RECEIVING PARTY DATA

Name:	UNITED MICROELECTRONICS CORP.
Street Address:	No.3, Li-Hsin Road 2, Science-Based Industrial Park
City:	Hsin-Chu City
State/Country:	TAIWAN

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	11538815

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Total Attachments: 2

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PATENT REEL: 018348 FRAME: 0572

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ASSIGNMENT OF INVENTION

In consideration of the payment by ASSIGNEE to ASSIGNOR of the sum of One Dollar (\$1.00), the receipt of which is hereby acknowledged, and for other good and valuable consideration.

Name:	Hung-Lin Shih Nationality: R.O.C.				
Address:	12F., No.46, Lane 476, Sec. 1, Guangfu Rd., Hsinchu City, Taiwan, R.O.C.				
Name:	Tsan-Chi Chu	Nationality: R.O.C.			
Address:	No.1, Alley 6, Lane 22, Tien-Mei 3 St., Hsin-Chu City, Taiwan, R.O.C.				
Hereby sells, as	ssigns and transfers to				
ASSIGNEE(S)):				
Name:	UNITED MICROELECTRO	ONICS CORP.			
Address:	No.3, Li-Hsin Road 2, Scien R.O.C.	nce-Based Industrial Park, Hsin-Chu City 300, Taiwan,			
and the succes		SIGNEE the entire right, title, and interest in and to			
	provements which are disclos	ed in the invention entitled:			
any and all imp	D OF MANUFACTURING COM	PLEMENTARY METAL OXIDE SEMICONDUCTOR			
any and all imp "METHO"	D OF MANUFACTURING COM STOR"				
nny and all imp "METHO TRANSI Which is four	D OF MANUFACTURING COM STOR"	PLEMENTARY METAL OXIDE SEMICONDUCTOR			
"METHO TRANSI Which is four (a)	D OF MANUFACTURING COM STOR" ad in: U.S. patent application execu	PLEMENTARY METAL OXIDE SEMICONDUCTOR atted on even date atted on			
"METHO TRANSI Which is four (a)	D OF MANUFACTURING COM STOR" ad in: U.S. patent application execu	PLEMENTARY METAL OXIDE SEMICONDUCTOR			

ASSIGNOR(S) (Inventors):

and, in and to, all Letters Patent to be obtained for said invention by the above application or any continuations, continuation-in-part, divisions, renewals, substitutes, or extensions thereof, and as to Letters Patent any reissue or re-examination thereof

ASSIGNOR hereby covenants that no assignment, sale, agreement or encumbrance has been or will be made or entered into which would conflict with this assignment;

ASSIGNOR further covenants that ASSIGNEE will, upon its request, be provided promptly with all pertinent facts and documents relating to said invention and said Letters Patent and legal equivalents as may be known and accessible to ASSIGNOR and will testify as to the same in any interference, litigation or proceeding related thereto and will promptly execute and deliver to ASSIGNEE or its legal representatives any and all papers, instruments or affidavits required to apply for, obtain, maintain, issue and enforce said application, said invention and said Letters Patent and said equivalents thereof which may be necessary or desirable to carry out the proposes thereof.

IN WITNESS WHEREOF, We have hereunto set hand and seal this OCT 0 1 2006(Date of signing). (請發明人務必簽署上列日期。)

(Type name of inventor)	Signature of INVENTOR	
Hung-Lin Shih	Hung-Lin Shih	, , , , , , , , , , , , , , , , , , ,
Tsan-Chi Chu	touchi clin	

RECORDED: 10/05/2006